

## Microwave Power Silicon Bipolar Transistor 5.0 W, 960–1215 MHz, 28V

M/A-COM Products Released - Rev. 053007

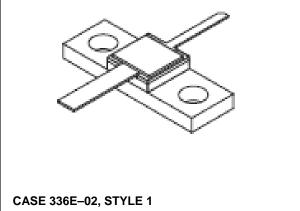
### Features

- Guaranteed performance @1.215GHz, 28Vdc
- Output power: 5.0W CW
- Minimum gain = 8.5dB, 10.3dB (Typ.)
- RF performance curves for 28 Vdc and 36 Vdc operation
- 100% tested for load mismatch at all phase angles with 10:1 VSWR
- · Hermetically sealed industry standard package
- Silicon nitride passivated
- Gold metallized, emitter ballasted for long life and resistance to metal migration
- Internal input matching for broadband operation

### **Description and Applications**

Designed for CW and long-pulsed common base amplifier applications, such as JTIDS and Mode S, in the 0.96 to 1.215 GHz frequency range with high overall duty cycles.

# Product Image



Maximum Ratings	Symbol	Value	Unit	
Collector–Emitter Voltage	V <sub>CES</sub>	55	Vdc	
Collector–Base Voltage	V <sub>CBO</sub>	55	Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	3.5	Vdc	
Collector Current — Continuous (1)	I <sub>C</sub>	1.25	mAdc	
Total Device Dissipation @ T <sub>A</sub> = 25°C (1) Derate above 25°C	PD	25 143	Watt mW/°C	
Storage Temperature Range	T <sub>stg</sub>	-65 to +200	°C	
Junction Temperature	TJ	200	°C	
THERMAL CHARACTERISTICS				

Characteristic	Symbol 3 1	Мах	Unit
Thermal Resistance, Junction to Case (2)	$R_{\theta JC}$	7.0	°C/W

NOTES:

- 1. These devices are designed for RF operation. The total device dissipation rating applies only when the devices are operated as RF amplifiers.
- Thermal Resistance is determined under specified RF operating conditions by infrared measurement techniques.

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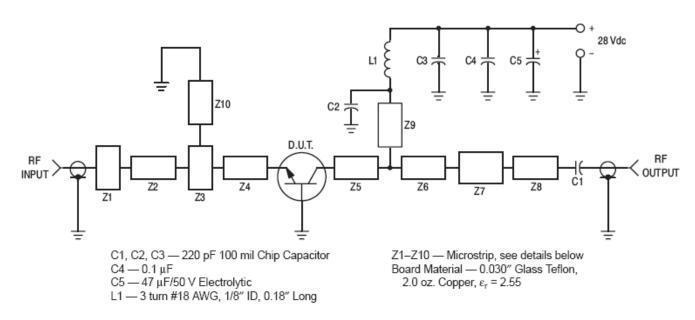
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#### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage ( $I_C = 25 \text{ mAdc}, V_{BE} = 0$ )	V <sub>(BR)CES</sub>	55	-	-	Vdc
Collector–Base Breakdown Voltage ( $I_C = 25 \text{ mAdc}, I_E = 0$ )	V <sub>(BR)CBO</sub>	55	-	_	Vdc
Emitter–Base Breakdown Voltage ( $I_E = 0.5 \text{ mAdc}, I_C = 0$ )	V <sub>(BR)EBO</sub>	3.5	_	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 28 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	_	_	1.0	mAdc
ON CHARACTERISTICS			•	1	1
DC Current Gain (I <sub>C</sub> = 500 mAdc, V <sub>CE</sub> = 5.0 Vdc)	h <sub>FE</sub>	20	-	100	_
DYNAMIC CHARACTERISTICS	·		•	•	•
Output Capacitance (V <sub>CB</sub> = 28 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	Cob	—	7.0	10	pF
FUNCTIONAL TESTS			•	1	1
Common–Base Amplifier Power Gain (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 5.0 W, f = 1215 MHz)	G <sub>PB</sub>	8.5	10.3	-	dB
Collector Efficiency (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 5.0 W, f = 1215 MHz)	η	45	55	-	%
Load Mismatch (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 5.0 W, f = 1215 MHz, VSWR = 10:1 All Phase Angles)	Ψ	No Degradation in Output Power			



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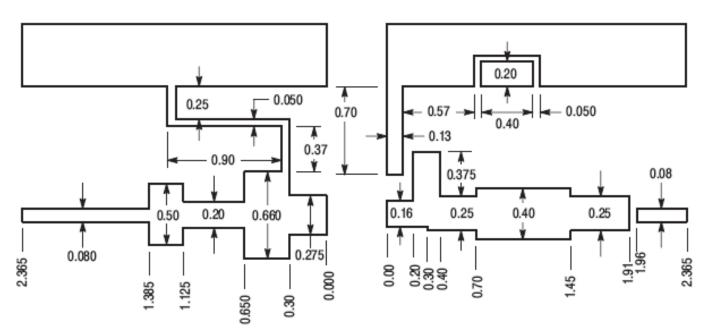
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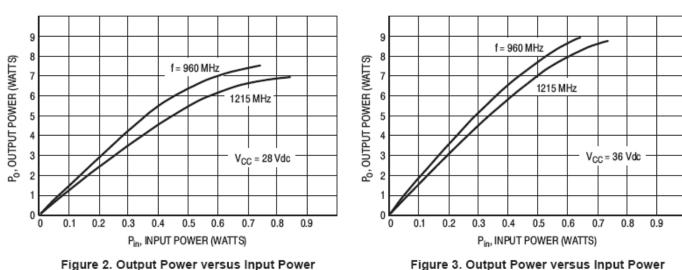


Figure 3. Output Power versus Input Power

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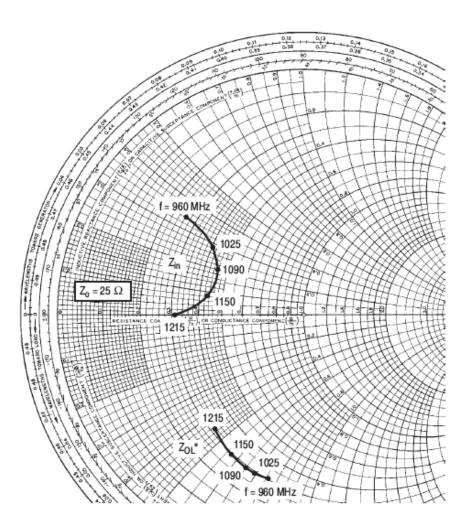


Figure 4. Series Equivalent Input/Output Impedances

Pout =	5 W,	V <sub>CC</sub> =	28 V
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f	Z <sub>in</sub>	Z <sub>OL</sub> *
MHz	OHMS	OHMS
960	6.5 + j8.5	7.4 - j18.9
1025	10.0 + j7.0	7.2 - j17.4
1090	11.2 + j4.9	7.1 - j16.3
1150	10.8 + j2.0	7.15 - j14.3
1215	7.8 + j0.0	7.8 - j11.2

Z<sub>OL</sub>\* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

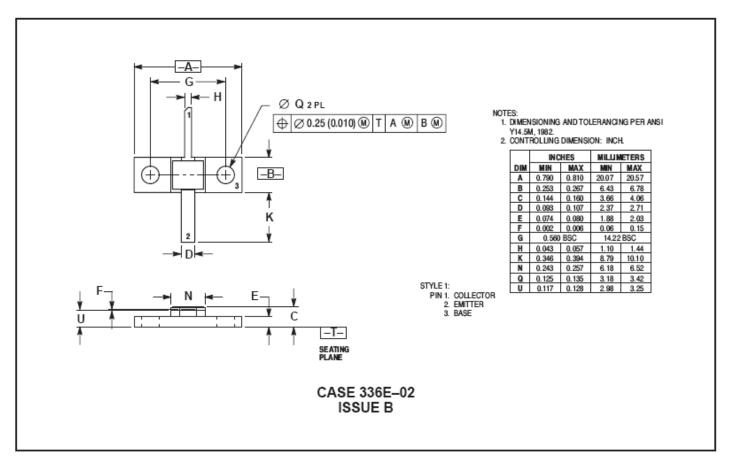
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### PACKAGE DIMENSIONS



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